Silicon Epitaxial Planar Switching Diode

Features

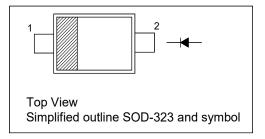
- AEC-Q101 Qualified
- Low Forward Voltage
- Fast Reverse Recovery Time
- Small Total Capacitance
- Halogen and Antimony Free(HAF), RoHS compliant

Application

• Ultra high speed switching

PINNING

PIN	DESCRIPTION			
1	Cathode			
2	Anode			



Absolute Maximum Ratings ($T_a = 25^{\circ}C$)

Parameter	Symbol	Value	Unit
Maximum (Peak) Reverse Voltage	V _{RM}	85	V
Reverse Voltage	V _R	80	V
Average Rectified Forward Current	I _{F(AV)}	100	mA
Maximum (Peak) Forward Current	I _{FM}	200	mA
Surge Forward Current (10 ms)	I _{FSM}	1	Α
Power Dissipation	P _{tot}	200	mW
Junction Temperature	Tj	150	°C
Storage Temperature Range	T _{stg}	- 55 to + 150	°C

Thermal Characteristics

Parameter	Symbol	Max.	Unit	
Thermal Resistance from Junction to Ambient 1)	Reja	625	°C/W	

¹⁾Device mounted on FR-4 substrate PC board, with minimum recommended pad layout.



1SS352-AH

Characteristics at $T_a = 25$ °C

Parameter	Symbol	Min.	Max.	Unit
Reverse Breakdown Voltage at $I_R = 10 \mu A$	V _{(BR)R}	80	-	V
Forward Voltage at I _F = 100 mA	V _F	-	1.2	V
Reverse Current at $V_R = 30 \text{ V}$ at $V_R = 80 \text{ V}$	I _R	-	0.1 0.5	μΑ
Total Capacitance at $V_R = 0 V$, $f = 1 MHz$	Ст	-	3	pF
Reverse Recovery Time at I_F = 10 mA, I_{RR} = 0.1 * I_R , V_R = 6 V, R_L = 100 Ω	t _{rr}	-	4	ns



Electrical Characteristics Curves

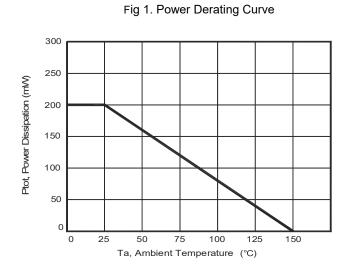


Fig 2. Total Capacitance vs. Reverse Voltage

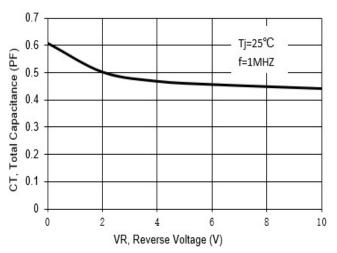
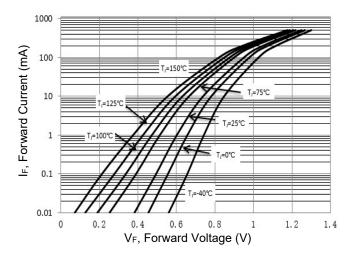


Fig 3. Reverse Current vs. Reverse Voltage

100
10
10
10
T_{j=150C}
T_{j=125C}
T_{j=10C}
T_{j=25C}
T_{j=25C}
T_{j=25C}
T_{j=40C}
T_{j=40C}
T_{j=40C}
T_{j=0C}
T_{j=0C}
T_{j=0C}
T_{j=0C}
VR, Reverse Voltage (V)

Fig 4. Forward Characteristics

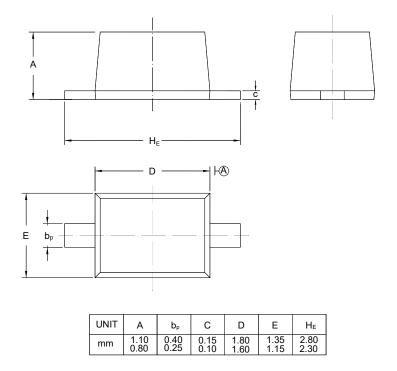




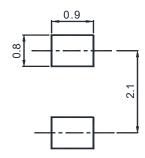
PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-323



Recommended Soldering Footprint



Packing information

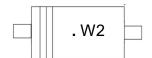
Package	Tape Width	Pitch		Reel Size		Dan Dani Danisin n Ossantitus
	(mm)	mm	(inch)	mm	(inch)	Per Reel Packing Quantity
SOD-323	8	4 ± 0.1	0.157 ± 0.004	178	7	3,000

Marking information

" W2 " = Part No.

" III " = Cathode line

"•" = HAF (Halogen and Antimony Free)



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